www.vishay.com

Hyperfast Rectifier, 75 A FRED Pt<sup>®</sup> Gen 5



## LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTE	RISTICS
I <sub>F(AV)</sub>	75 A
V <sub>R</sub>	1200 V
V <sub>F</sub> at I <sub>F</sub> at 125 °C	2.3 V
t <sub>rr</sub>	32 ns
T <sub>J</sub> max.	175 °C
Package	TO-247AD 2L
Circuit configuration	Single

#### **FEATURES**

- Hyperfast and optimized Qrr
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## **DESCRIPTION / APPLICATIONS**

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

### **MECHANICAL DATA**

**Case:** TO-247AD 2L Molding compound meets UL 94 V-0 flammability rating **Terminals**: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATING	S			
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Repetitive peak reverse voltage	V <sub>RRM</sub>		1200	V
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 90 °C, D = 0.50	75	
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_{C}$ = 45 °C, $t_{p}$ = 10 ms, sine wave	395	А
Repetitive peak forward current	I <sub>FRM</sub>	T <sub>C</sub> = 90 °C, D = 0.50, f = 20 kHz	150	
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C

ELECTRICAL SPECIFICATIONS	(T <sub>J</sub> = 25 °	5 °C unless otherwise specified)				
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	1200	-	-	
Forward voltage	VF	I <sub>F</sub> = 75 A	-	2.7	3.3	V
Forward voltage	۷F	I <sub>F</sub> = 75 A, T <sub>J</sub> = 125 °C	-	2.3	-	
Reverse leakage current		V <sub>R</sub> = V <sub>R</sub> rated	-	-	50	
neverse leakage current	IR	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	36	-	pF
Series inductance	L <sub>S</sub>	Measured to lead 5 mm from package body	-	8	-	nH

 Revision: 18-Sep-2023
 1
 Document Number: 96889

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

HALOGEN FREE

**RoHS** COMPLIANT



DYNAMIC RECOVERY CHA	RACTER	<b>STICS</b> (T <sub>J</sub> = 25	°C unless otherwi	se specit	fied)		
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt =	100 A/µs, V <sub>R</sub> = 30 V	-	32	-	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	140	-	ns
		T <sub>J</sub> = 125 °C		-	200	-	
Peak recovery current	1	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 50 A dI <sub>F</sub> /dt = 600 A/µs	-	18	-	А
Feak recovery current	IRRM	T <sub>J</sub> = 125 °C	$V_{\rm B} = 400 \text{ V}$	-	35	-	~
Reverse recovery charge	T <sub>J</sub> = 25 °C	-n	-	1100	-	nC	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	3550	-	no
Poverse receivery time	+	T <sub>J</sub> = 25 °C		-	100	-	20
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	154	-	ns
Peak recovery current		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 75 A dI <sub>F</sub> /dt = 1000 A/µs	-	31	-	А
Peak recovery current	IRRM	T <sub>J</sub> = 125 °C	$V_{\rm R} = 800  \text{V}$	-	58	-	A
Poverse receivery charge	0	T <sub>J</sub> = 25 °C		-	1820	-	nC
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	5300	-	

THERMAL - MECHANICAL SPECIFIC	CATIONS	;				
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	-	0.36	°C/W
Weight			-	5.5	-	g
Weight			-	0.2	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C
Marking device		Case style: TO-247AD 2L		E5PX	7512L	

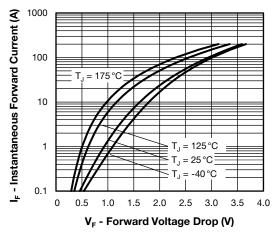


Fig. 1 - Forward Voltage Drop Characteristics

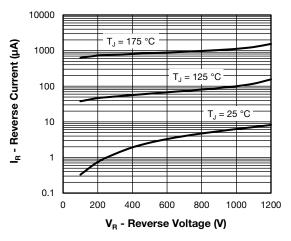


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



# **VS-E5PX7512L-N3**

**Vishay Semiconductors** 

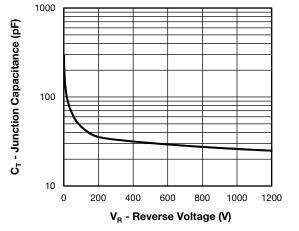


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

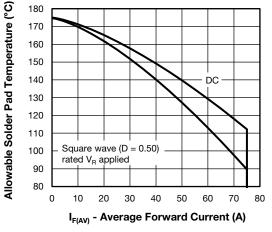


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

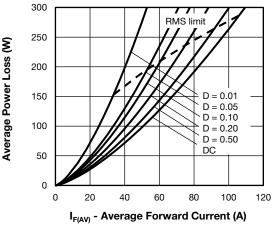


Fig. 5 - Forward Power Loss Characteristics

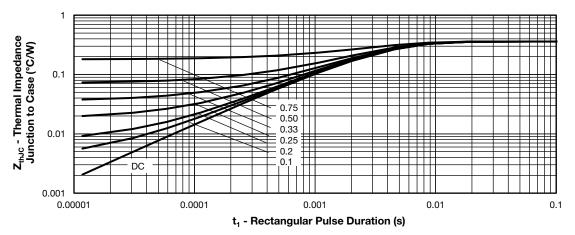


Fig. 6 - Transient Thermal Impedance, Junction to Case

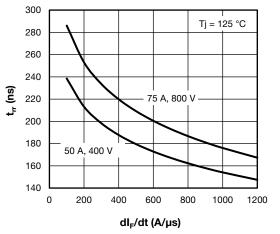
Revision: 18-Sep-2023

3

Document Number: 96889

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





www.vishay.com

ISHAY

Fig. 7 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

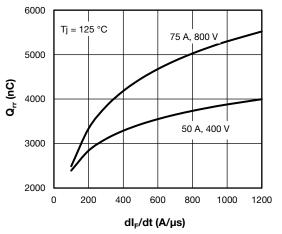


Fig. 8 - Typical Reverse Recovery Charge vs. dI<sub>F</sub>/dt

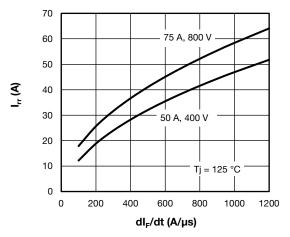


Fig. 9 - Typical Reverse Recovery Current vs. dI<sub>F</sub>/dt



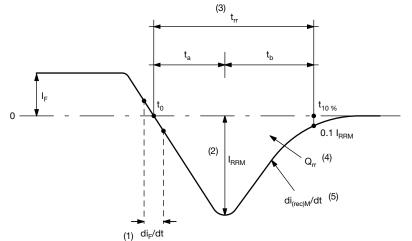


Fig. 10 - Reverse Recovery Waveform and Definitions

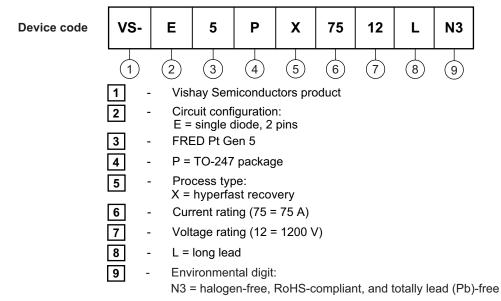
#### Notes

- $\binom{1}{1}$  di<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> - peak reverse recovery current
- <sup>(3)</sup>  $t_{rr}$  reverse recovery time measured from  $t_0$ , crossing point of negative going I<sub>F</sub>, to point  $t_{10\%}$ , 0.1 I<sub>RRM</sub> <sup>(4)</sup>  $Q_{rr}$  area under curve defined by  $t_0$  and  $t_{10\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t) dt$$

<sup>(5)</sup> di<sub>(rec)</sub>M/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

#### **ORDERING INFORMATION TABLE**



ORDERING INFORMATI	<b>ON</b> (Example)		
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-E5PX7512L-N3	25	500	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS		
www.vishay.com/doc?95536		
www.vishay.com/doc?95648		

Revision: 18-Sep-2023

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2024 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2024